

EE4C10 Analog Circuit Design Fundamentals

Homework Assignment IV

Tzong Lin Chua

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Simulation Files

Each question with simulation files will have their respective subfolder.

Running the simulation files should be able to directly plot the graphs used (configured in the *.plt file). The folders for each question are arranged as follows after extracting:

spice
q4

Problem 1

(a) Small-signal gain, A_v

$$G_m = g_m$$

$$R_{out} = R_D$$

$$A_V = -g_m R_D$$

Thermal noise of:

1. Resistor, R_D

Output noise current and voltage,

$$S_{i_{out},th} = \frac{4kT}{R_D}$$

$$\begin{aligned} S_{v_{out},th} &= S_{i_{output}} R_{out}^2 \\ &= 4kT R_D \end{aligned}$$

2. Transistor, M

Output noise current and voltage,

$$S_{i_{out},th} = 4kT \gamma g_m$$

$$\begin{aligned} S_{v_{out},th} &= S_{i_{output}} R_{out}^2 \\ &= 4kT \gamma g_m R_D^2 \end{aligned}$$

Total output thermal noise,

$$\begin{aligned} S_{v_{out},th} &= 4kTR_D + 4kT\gamma g_m R_D^2 \\ &= 4kTR_D^2(\gamma g_m + \frac{1}{R_D}) \end{aligned}$$

Total input thermal noise,

$$\begin{aligned} S_{v_{in},th} &= \frac{S_{v_{out},th}}{A_V^2} \\ &= \frac{4kT}{g_m}(\gamma + \frac{1}{g_m R_D}) \end{aligned}$$

(b) Flicker noise PSD at:

1. Input

$$\begin{aligned} S_{in,\frac{1}{f}} &= \frac{K}{C_{OX}WL} \cdot \frac{1}{f} \\ &= \frac{1.11 \times 10^{-12} \text{ V}^2}{f} \frac{1}{Hz} \end{aligned}$$

2. Output

$$\begin{aligned} S_{in,\frac{1}{f}} &= S_{in,\frac{1}{f}} A_V^2 \\ &= \frac{K(g_m R_D)^2}{C_{OX}WL} \cdot \frac{1}{f} \\ &= \frac{4.0 \times 10^{-11} \text{ V}^2}{f} \frac{1}{Hz} \end{aligned}$$

(c) $\frac{1}{f}$ noise corner frequency

$$\begin{aligned} S_{in,\frac{1}{f}}(f_c) &= S_{v_{in},th}(f_c) \\ \frac{K}{C_{OX}WL} \cdot \frac{1}{f_c} &= \frac{4kT}{g_m}(\gamma + \frac{1}{g_m R_D}) \\ f_c &= \frac{K}{C_{OX}WL} \cdot \frac{1}{\frac{4kT}{g_m}(\gamma + \frac{1}{g_m R_D})} \\ &= 48.3kHz \end{aligned}$$

(d) RMS integrated output noise voltage,

$$\begin{aligned} v_{rms,noise,out} &= \sqrt{\int_{10^3}^{10 \times 10^6} \frac{K(g_m R_D)^2}{C_{OX}WL} \cdot \frac{1}{f} df + 4kTR_D^2(\gamma g_m + \frac{1}{R_D})\Delta f} \\ &= \sqrt{[\frac{K(g_m R_D)^2}{C_{OX}WL} \ln(f) + 4kTR_D^2(\gamma g_m + \frac{1}{R_D})]_{10^3}^{10 \times 10^6}} \\ &= 9.30 \times 10^{-5} \frac{V}{\sqrt{Hz}} \end{aligned}$$

(e) RMS integrated output noise voltage,

$$\begin{aligned} v_{rms,noise,out} &= \sqrt{\int_{10^3}^{10 \times 10^6} \frac{K(g_m R_D)^2}{C_{OX}WL} \cdot \frac{1}{f} df + 4kTR_D^2(\gamma g_m + \frac{1}{R_D})\Delta f} \\ &= \sqrt{[\frac{K(g_m R_D)^2}{C_{OX}WL} \ln(f) + 4kTR_D^2(\gamma g_m + \frac{1}{R_D})]_{10^3}^{10 \times 10^3}} \\ &= 9.98 \times 10^{-6} \frac{V}{\sqrt{Hz}} \end{aligned}$$

(f) SNR,

$$\begin{aligned} SNR &= 20\log(\frac{V_{rms,signal}}{V_{rms,noise}}) \\ &= 80dB \end{aligned}$$

Problem 2

Output resistance, transconductance and gain of amplifier,

$$\begin{aligned} R_{out} &= (r_o + R_s) + g_m R_s r_o \\ G_m &= \frac{g_m}{(1 + \frac{R_s}{r_o}) + g_m R_s} \\ A_V &= \frac{g_m [(r_o + R_s) + g_m R_s r_o]}{(1 + \frac{R_s}{r_o}) + g_m R_s} \end{aligned}$$

(a) Thermal noise from:

Transistor, M

$$\begin{aligned} \overline{v_{M,out}^2} &= 4kT\gamma g_m R_{out}^2 \\ &= 4kT\gamma g_m [(r_o + R_s) + g_m R_s r_o]^2 \end{aligned}$$

Resistor, R_s

$$\begin{aligned} \frac{V_S - V_o}{r_o} &= -g_m V_s \\ V_o &= (1 + g_m r_o) V_s \end{aligned}$$

$$\overline{v_{R_s,out}^2} = 4kT R_s (1 + g_m r_o)^2$$

Total output noise voltage,

$$\overline{v_{n,out}^2} = 4kT\gamma g_m [(r_o + R_s) + g_m R_s r_o]^2 + 4kT R_s (1 + g_m r_o)^2$$

(b) Ratio between thermal noise,

$$\begin{aligned} \frac{\overline{v_{M,out}^2}}{\overline{v_{R_s,out}^2}} &= \frac{4kT\gamma g_m [(r_o + R_s) + g_m R_s r_o]^2}{4kT R_s (1 + g_m r_o)^2} \\ &= \frac{\gamma g_m [(r_o + R_s) + g_m R_s r_o]^2}{R_s (1 + g_m r_o)^2} \\ &\approx \gamma g_m R_s \end{aligned}$$

(c) Input referred thermal noise,

$$\begin{aligned} \overline{v_{n,in}^2} &= \frac{\overline{v_{n,out}^2}}{A_v^2} \\ &= \{4kT\gamma g_m [(r_o + R_s) + g_m R_s r_o]^2 + 4kT R_s (1 + g_m r_o)^2\} \left[\frac{(1 + \frac{R_s}{r_o}) + g_m R_s}{g_m [(r_o + R_s) + g_m R_s r_o]} \right]^2 \\ &= 6.4653 \times 10^{-16} \frac{V^2}{Hz} \end{aligned}$$

Problem 3

(a) Since the circuit is symmetrical the differential noise due to the current mirrors, M_{N3} and M_{N4} is 0.

$$\overline{v_{n,diff,out}^2} = 0 \frac{V^2}{Hz}$$

(b) Common mode noise at output.

Noise current spectrum density at source of M_{N4} ,

$$\begin{aligned} \overline{i_{n,M_{N3}}^2} &= \frac{4kT\gamma g_{m4}^2}{g_{m3}} \\ \overline{i_{n,M_{N4}}^2} &= 4kT\gamma g_{m4} \\ \overline{i_n^2} &= \frac{4kT\gamma g_{m4}^2}{g_{m3}} + 4kT\gamma g_{m4} \\ &= 4kT\gamma g_{m4} \left(1 + \frac{g_{m4}}{g_{m3}}\right) \end{aligned}$$

Input referred noise voltage,

$$\begin{aligned}\overline{v_{n,in}^2} &= \frac{\overline{i_n^2}}{4g_{m1}^2} \\ &= \frac{g_{m4}kT\gamma}{g_{m1}^2} \left(1 + \frac{g_{m4}}{g_{m3}}\right)\end{aligned}$$

Output referred common-mode noise,

$$\begin{aligned}A_{CM-CM}(s) &= \frac{-g_{m1}}{g_{m2} + sC_L} \\ \overline{v_{n,out}^2} &= \overline{v_{n,in}^2} A_{CM-CM}(s)^2 \\ &= \frac{g_{m4}kT\gamma}{g_{m1}^2} \left(1 + \frac{g_{m4}}{g_{m3}}\right) \left[\frac{g_{m1}}{g_{m2} + sC_L}\right]^2 \\ &= \frac{g_{m4}kT\gamma}{(g_{m2} + sC_L)^2} \left(1 + \frac{g_{m4}}{g_{m3}}\right) \\ &= \frac{2g_{m4}kT\gamma}{(g_{m2} + sC_L)^2}\end{aligned}$$

Doubling I_B and W_3 , will not increase the current at the amplifier or g_{m3} . Therefore

$$\begin{aligned}\overline{v_{n,out}^2} &= \frac{g_{m4}kT\gamma}{(g_{m2} + sC_L)^2} \left(1 + \frac{g_{m4}}{g_{m3}}\right) \\ &= \frac{2g_{m4}kT\gamma}{(g_{m2} + sC_L)^2}\end{aligned}$$

1. Total differential input and output noise PSD,

$$\begin{aligned}Z_{out}(s) &= \frac{1}{g_{m2} + sC_L} \\ A_{DM-DM} &= \frac{g_{m1}}{g_{m2} + sC_L} \\ \overline{v_{n,MN1\&MN2}(s)^2} &= \left(\frac{1}{g_{m2} + sC_L}\right)^2 (4kT\gamma g_{m1} + 4kT\gamma g_{m1}) \\ &= \frac{8kT\gamma g_{m1}}{(g_{m2} + sC_L)^2} \\ \overline{v_{n,MP1\&MP2}(s)^2} &= \left(\frac{1}{g_{m2} + sC_L}\right)^2 (4kT\gamma g_{m2} + 4kT\gamma g_{m2}) \\ &= \frac{8kT\gamma g_{m2}}{(g_{m2} + sC_L)^2} \\ \overline{v_{n,out}^2}(s) &= \frac{8kT\gamma}{(g_{m2} + sC_L)^2} (g_{m1} + g_{m2}) \\ \overline{v_{n,in}^2} &= \frac{8kT\gamma}{g_{m1}^2} (g_{m1} + g_{m2})\end{aligned}$$

2. Integrated differential output thermal noise,

$$\begin{aligned}
\overline{v_{n,out}^2}(s) &= \frac{8kT\gamma}{(g_{m2} + sC_L)^2} (g_{m1} + g_{m2}) \\
&= \frac{8kT\gamma(g_{m1} + g_{m2})}{g_{m2}^2(1 + \frac{sC_L}{g_{m2}})^2} \\
&= \frac{8kT\gamma(g_{m1} + g_{m2})}{g_{m2}^2} \frac{1}{(1 + \frac{sC_L}{g_{m2}})^2}
\end{aligned}$$

$$\begin{aligned}
ENBW &= \frac{\pi}{2} \frac{g_{m2}}{2\pi C_L} \\
&= \frac{g_{m2}}{4C_L}
\end{aligned}$$

$$\begin{aligned}
v_{rms}^2 &= \frac{8kT\gamma(g_{m1} + g_{m2})}{g_{m2}^2} \times ENBW \\
&= \frac{2kT\gamma(g_{m1} + g_{m2})}{g_{m2}C_L}
\end{aligned}$$

3. Integrated differential output thermal noise,

$$\begin{aligned}
v_{rms}^2 &= \frac{8kT\gamma(g_{m1} + g_{m2})}{g_{m2}^2} \times ENBW \\
&= \frac{2kT\gamma(g_{m1} + g_{m2})}{g_{m2}C_L} \\
&= 2.76 \times 10^{-08} \frac{V^2}{Hz}
\end{aligned}$$

Problem 4

Step:

1. Gain and BW of amplifier

$$\begin{aligned}
A_{DM-DM} &= \frac{g_{m1}}{g_{m2} + sC_L} \\
f_c &= \frac{g_2}{2\pi C_L}
\end{aligned}$$

2.